Crystal Growth: Physics, Technology and Modeling

Stanisław Krukowski & Michał Leszczyński Institute of High Pressure Physics PAS 01-142 Warsaw, Sokołowska 29/37 e-mail: <u>stach@unipress.waw.pl</u>, <u>mike@unipress.waw.pl</u>

> Zbigniew Żytkiewicz Institute of Physics PAS 02-668 Warsaw, Al. Lotników 32/46 E-mail: <u>zytkie@ifpan.edu.pl</u>

Lecture 11. Shape selection during growth and shape stability

http://www.unipress.waw.pl/~stach/cg-2021-22

Scope

- Growth habit flat and rough surfaces
- Flat surfaces evolution of the faces
- Face stability
- Morphological stability of the rough surfaces
- Instability of the flat crystallization face
- Instability of spherical nucleus
- Shape evolution emergence of dendrite
- Cellular instability

Basic growth modes

- Flat surface
 - Slow kinetics
 - High supersaturation
 - Growth shape collection of crystallographic planes

- Rough surfaces
 - Fast kinetics
 - Small supersaturation
 - Surface shape follows thermodynamics potential distribution

Growth habit – set of crystallographic planes

- Crystallographic plane identification Miller (ijk) or Miller-Bravais (ijkl) indices faces should be associated with the planes
- Face fraction of crystallographic plane face area $S_{(iik)}$
- Face weights $w_{(ijk)}$

$$w_{(ijk)} = \frac{S_{(ijk)}}{\sum_{(ijk)} S_{(ijk)}}$$

Growth shape

- Shape set of the surfaces (2-d objects) described by mathematical relations
- Flat surface crystals: Miller or Miller-Bravais indices and their weights
- Flat surface: equation describing its shape in 3-d space (single or some combination)

Flat surfaces – growth rates

• Growth rate at crystallographic plane (face) $- R_{hkl}$

$$R_{hkl} = \frac{\left[\vec{r}_{hkl}(t + \Delta t) - \vec{r}_{hkl}(t)\right] \cdot \vec{n}_{hkl}}{\Delta t}$$

- Shape change geometric translation in the direction normal to the plane
- Shape evolution during growth some faces may arise or disappear face morphological stability
- Growth rates may depend on the local thermodynamic conditions

Growth sectors, growth sector boundaries, growth bands



GS – growth sectors, GSB – growth sector boundaries , GB – growth bands, S - nucleus.



Politechnika Łódzka

7

Face stability - (growth of potassium dichromate $- K_2 Cr_2 O_7 - KBC$)



Stable wall

Unstable wall

J. Prywer: "Crystal faces existence and morphological stability from crystallographic perspective" Cryst. Growth Des. 3 (2003) 593–598. 8



Politechnika Łódzka

Tangential growth rate

$$\frac{dl_{hkl}}{dt} = \frac{R_{h_1k_1l_1}sin(\gamma) + R_{h_2k_2l_2}sin(\alpha) - R_{hkl}sin(\alpha + \gamma)}{sin(\alpha)sin(\gamma)}$$

Tangential velocity dl_{hkl}/dt determines the face evolution: (i) $dl_{hkl}/dt > 0$ face (hkl) increases (ii) $dl_{hkl}/dt = 0$ face (hkl) in not changed (iii) $dl_{hkl}/dt > 0$ face (hkl) decreases



J. Prywer: "Crystal faces existence and morphological stability from crystallographic perspective" *Cryst. Growth Des.* **3** (2003) 593–598.



9

Morphological stability of the faces

face (001) $\alpha = 54.90 \ arc \ deg, \gamma = 72.79 \ arc \ deg$

prążek	$\frac{R_{(001)}}{R_{(011)}}$	$\frac{R_{(001)}}{R_{(0\bar{1}1)}}$	$\frac{\mathrm{d}l_{(001)}}{\mathrm{d}t}$
0-1	0.52	0.46	4.63
1-2	0.65	0.72	2.93
2-3	0.50	0.50	3.15
3-4; 4-5	1.14	1.14	2.05
5-6	1.20	1.20	1.92
6-7	1.25	1.25	1.81
7-8	1.05	1.05	2.26
8-9; 9-10	1.25	1.25	1.81
10-11	2.00	2.00	0.14
11-12	2.25	2.25	0.13
12-13	0.89	1.14	1.92
13-14	0.98	1.77	1.30



J. Prywer: "Crystal faces existence and morphological stability from crystallographic perspective" Cryst. Growth Des. 3 (2003) 593–598. 10



04.01.2022 – Shape selection

Morphological stability of the walls

Wall (010) $\alpha = 30.80 \ arc \ deg, \gamma = 27.01 \ arc \ deg$

prażek	$R_{(010)}$	$R_{(010)}$	$dl_{(010)}$
Γ - ζ -	$R_{(01\overline{1})}$	$R_{(011)}$	dt
0-1	1.00	0.72	2.47
1-2; 2-3	1.14	1.14	0.00
3-4	1.20	1.20	-0.42
4-5	1.25	1.25	-0.79
5-6	1.05	1.05	0.67
6-7	1.25	1.25	-0.79
7-8; 8-9	1.00	1.00	1.03
9-10	1.40	1.40	-1.88
10-11; 11-12	1.05	1.05	0.67
12-13	0.89	1.14	0.99
13-14	0.98	1.77	-1.28



J. Prywer: "Crystal faces existence and morphological stability from crystallographic perspective" *Cryst. Growth Des.* **3** (2003) 593–598.



Morphological stability of the faces



J. Prywer: "Crystal faces existence and morphological stability from crystallographic perspective" *Cryst. Growth Des.* **3** (2003) 593–598.



Politechnika Łódzka

 $\alpha = 14.84 \ arc \ deg, \gamma = 15.96 \ arc \ deg$

Face $(02\overline{1})$

12

Morphological stability of the faces – KBC $(0\overline{1}0)$ surface



J. Prywer: "On the crystal geometry influence on the growth of fast-growing surfaces", *J. Phys. and Chem. of Solids* **63** (2002) 493–501.



Bravais-Friedel-Donnay-Harker (BFDH) law

Morphological weight (MI) of the faces is proportional to interplanar distance

$$d_{h_1k_1l_1} > d_{h_2k_2l_2} \Longrightarrow \mathrm{MI}_{h_1k_1l_1} > \mathrm{MI}_{h_2k_2l_2}$$

 $R_{hkl} \propto 1/d_{hkl}$

MI (morphological importance)

G. Friedel, Leçon de Cristallographie, Hermann, Paris (1911).

A. Bravais, Études Cristallographiques, Gauthier-Villard, Paris (1913).

J.D.H. Donnay, D. Harker, Am. Mineral. 22 (1937) 446.



Face morphological importance (MI)

All faces have the same growth rate – morphological importance is different



J. Prywer: "Kinetic and Geometric Determination of the Growth Morphology of Bulk Crystals: Recent Developments" *Prog. Cryst. Growth Charact.* **50** (2005) 1–38.



15

Growth rate rules

• Attachment energy rule (Hartmann et al.)

 $R_{hkl} \propto E_{hkl}$

 E_{hkl} – attachment energy – energy change during attachment of new atomic layer at given crystallographic plane

Calcium oxalate - CaC₂O₄*(H₂O)_x







R. C. Waltion, J.P. Kavanagh, B. R. Heywoodb, P. N. Rao, *Calcium oxalates grown in human urine under different batch conditions.* J. Cryst. Growth 284 (2005) 517



Pharmaceutics

Ascorbic Acid – C_6H_8O



Vitamin C crystals grown from water solution by slow evaporation.

A. Arslants, W.C. Emler, R. Yazici, D. M. Kalyon, *Crystal Habit Modification of Vitamin C (L-Ascorbic Acid) due to Solvent Effects.* Turk. J. Chem. 28 (2004) 255



Na₂SiF₆ – crystal analogy to ice



Z. Ulanowski, E. Hessea, P. H. Kayea, A. J. Baranb, R Chandrasekhar, *Scatterring of lighy from atmospheric ice analogues*.

J. Qant. Spetcr. Radiat. Transfer 79-80 (2003) 1091



Na₂SiF₆- crystal analogy to ice



Z. Ulanowski, E. Hessea, P. H. Kayea, A. J. Baranb, R Chandrasekhar, *Scatterring of lighy from atmospheric ice analogues .* J. Qant. Spetcr. Radiat. Transfer 79-80 (2003) 1091



Na_2SiF_6 – crystal analogy to ice





Crystal grown in Institute of Physics Lodz University of Technology

Crystal grown in Hertforshire University http://strc.herts.ac.uk/ls/analog.html

M. J. Krasiński, J. Prywer: "Growth morphology of sodium fluorosilicate crystals and its analysis in base of relative growth rates" – J. Cryst. Growth 303 (2007) 105–109. 21



Politechnika Łódzka

Morphological stability – preservation of the shape during growth

• Morphology change – emergence of the new shape (local difference) is defined as the shape (morphology) instability

Instability mode:

- Surface (plane)
- Edge corner
- Sphere

Linear stability theory

• **Basic solution (stationary)**

$$f = f_o(\vec{r}, t) = f(\vec{r} - \vec{v}t)_o$$

• Perturbed solution

 $f = f_o(\vec{r}, t) + \delta(\vec{r}, t) \qquad |\delta(\vec{r}, t)| \ll |f_o(\vec{r}, t)|$

• Linearization of the equation – matrix linear equation

$$\frac{d\delta(\vec{r},t)}{dt} = A \,\delta(\vec{r},t)$$

• Solution of the linear equation

$$\delta(\vec{r},t) = \delta(\vec{r}) \exp(\lambda t)$$

 λ – Lyapunov exponent

 $\begin{array}{ll} \lambda > 0 & unstable \\ \lambda < 0 & stable \end{array}$

Flat crystallization front – growth from solution

• Temperature and concentration equations (solid, liquid)

$$\frac{\partial T}{\partial t} = D_{th}\Delta T \qquad \qquad \frac{\partial T}{\partial t} = D_{th}\Delta T$$
$$C_s = const(t) \qquad \qquad \frac{\partial C_l}{\partial t} = D_l\Delta C_l$$

• Boundary conditions z = vt

$$T_{s} = T_{l} = T_{M} \left(1 + \frac{2\Gamma}{R} + m_{l}C_{l} \right) \qquad \kappa_{s} \nabla T_{s} = \kappa_{k} \nabla T_{l} + \vec{v}H$$
$$D_{l} \nabla C_{l} = \vec{v}(k-1)C_{l}$$

• Solution – stationary in the interface coordination system

Flat crystallization front

• Concentration

$$C_{l} = C_{s} + C_{s} \frac{1-k}{k} \exp\left[-\frac{\nu z}{D}\right]$$
$$= C_{s} + \frac{GD}{\nu} \exp\left[-\frac{\nu z}{D}\right]$$

G – solute gradient at interface



Temperature $T_{l,s} = T_M - \frac{G_{l,s}D_{l,s}}{v} \left\{ 1 - exp \left[-\frac{vz}{D_{th,l,s}} \right] \right\}$





Liquid superooling $G_L < 0$

No liquid superooling $G_L > 0$

Constitutional supercooling at flat front

• Effective melting temperature: $T_1 = T_M + m C_l$



• Constitutive supercooling condition: $G_l < m G$

J. W. Rutter and B. Chalmers, Can. J. Phys. 31 (1953) 15 W. A. Tiller, J. W. Rutter, K. A. Jackson and B. Chalmers, Acta Met. 1 (1953) 729

Mullins –Sekerka theory of morphological stability



W.W. Mullins & R.F. Sekerka, J. Appl. Phys. 35 (1964) 444

Mullins –Sekerka instability of flat surface – cellular growth

• Instability mechanism

Cellular interface





R. Trvedi et al. J. Cryst. Growth 222 (2001) 365

Instability of growing spherical nucleus – Mullins-Sekerka theory

Diffusion

Boundary condition

$$\frac{\partial C}{\partial t} = D\Delta C = 0$$

$$C = C_o \left(1 - \frac{2\Gamma}{R} \right)$$

Stationary solution

$$C(r) = C_1 + \frac{C_2}{r}$$

• Linear stability analysis

 $C(\vec{r},t) = C(r) + \delta C(\vec{r},t) = C(r) + \delta C_1(\vec{r})exp(\lambda t)$

 $R(\vec{r},t) = R + \delta(t)Y_l^m(\theta,\varphi) = R + \delta_o Y_l^m(\theta,\varphi)exp(\lambda t)$

Mullins & Sekerka result (Lyapunov exponent)

$$\lambda = \frac{D(l-1)}{GR^2} \left[G - \frac{\Gamma c_o(l+1)(l+2)}{R^2} \right]$$

 $R > 7R_{cr} \quad \lambda > 0 \quad - \text{ unstable} \\ R < 7R_{cr} \quad \lambda < 0 \quad - \text{ stable}$

 $R_{cr} = \frac{2\Gamma}{\sigma} = \frac{2\gamma}{\Delta H} \frac{c_{eq}}{c_{\infty} - c_{eq}}$

W.W. Mullins & R.F. Sekerka, J. Appl. Phys. 34 (1963) 323

Side instability – evolution of dendrite - sidebranching

Dendrite geometry – side has larger radius



S.D.P. Corrigan et al. Phys. Rev E 60 (1999) 7217



S.C. Huang & M.E. Glicksman, Acta Metall. 29 (1981) 701

Edge instability in diffusion field

Polyhedral shape \rightarrow Edge instability \rightarrow Needle effect \rightarrow Higher rate ٠

Angular access





R.F Xiao, J.I.D. Alexander & F. Rosenberger, Phys. Rev A 38 (1988) 2447

φ = 0.69

$$\frac{b}{T} = 0.36$$

Edge instability in ballistic/diffusive transport field

• Polyhedral shape \rightarrow Edge instability \rightarrow needle effect \rightarrow higher rate



Fig. 7. Ballistic and diffusive transport modes: (a) $\lambda = 100 a$; (b) $\lambda = 10 a$, $L \approx 400 a$; (c) $\lambda = 50 a$, $L \approx 100 a$; (d) $\lambda = 50 a$, $L \approx 400 a$. The other parameters are: $\epsilon = 6.0$, $\sigma = 1999$ and $\xi = 0.0$.



S. Krukowski & J.C. Tedenac, J. Cryst. Growth 203 (1999) 269

Edge instability – evolution to dendrite

• Polyhedral shape \rightarrow Edge instability \rightarrow needle effect \rightarrow higher rate



• Side instability \rightarrow sidebranching \rightarrow dendrites

S. Krukowski & J.C. Tedenac, J. Cryst. Growth 203 (1999) 269

Snow crystals - dendrites



http://www.its.caltech.edu/~atomic/snowcrystals/photos/photos.htm

Microscopic scenario of instability

 Morphological instability - step motion perturbation – coupling of transport and surface dynamics



A. Chernov, J. Cryst. Growth 264 (2004) 599

Acknowledgments

For kind permission to use lecture material and help in preparation of this lecture to prof. dr hab. Jolanta Prywer from Institute of Physics of Lodz University of Technology



Politechnika Łódzka

Literature

- Handbook of Crystal Growth, vol. 1. Fundamentals, vols. 2. Bulk Crystal Growth, vol. 3 Thin Films and Epitaxy, ed. D.T.J. Hurle, Elsevier, Amsterdam 1994
- M.M. Faktor and I. Garreth, Growth of Crystals from the Vapour, Chapman and Hall, London, 1974
- F. Rosenberger, Fundamentals of Crystal Growth, Springer, Berlin, 1979
- A. Zangwill, Physics at Surfaces, Cambridge Univ. Press, Cambridgge 1987
- Crystal Growth. An Introduction, ed. P. Hartmann, North-Holland, Amsterdam, 1973
- Crystal Growth ed. B.R. Pamplin, Pergamon, Oford, 1980
- G.B. Stringfellow, Organometallic Vapor Phase Epitaxy: Theory and Practise, Academic Press, Boston, 1989
- W. Monch, Semiconductor Surfaces and Interfaces, Springer, Berlin, 1993